Accepted Manuscript

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PII: S0013-4686(18)31334-3

DOI: 10.1016/j.electacta.2018.06.046

Reference: EA 32039

To appear in: Electrochimica Acta

Received Date: 10 May 2018 Revised Date: 29 May 2018 Accepted Date: 6 June 2018

Please cite this article as: T.P. Nguyen, T.T. Ha, T.T. Nguyen, N.P. Ho, T.D. Huynh, Q.V. Lam, Effect of Cu²⁺ ions doped on the photovoltaic features of CdSe quantum dot sensitized solar cells, *Electrochimica Acta* (2018), doi: 10.1016/j.electacta.2018.06.046.

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Effect of Cu²⁺ ions doped on the Photovoltaic features of CdSe

Quantum Dot sensitized Solar Cells

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Abstract.

In this paper, we have succeeded in preparing the Quantum dots Solar cells with the high efficiency of 4.22% based on Cu²⁺ ions doped on CdSe Quantum dots by Successive ionic layer absorption and reaction. There are significant effects of Cu²⁺ ions on optical, physical, chemical and photovoltaic features of QDSSCs. As a result, the current density of the QDSSCs increased dramatically from 12mA/cm² for pure CdSe QDs to 19.915mA/cm² for Cu²⁺ ions doped on pure CdSe QDs. In fact, Cu²⁺ dopant rise in the conduction band of pure CdSe QDs, reduces recombination, enhances the efficiency of high harvesting, improve the charge transfer and collection. In addition, Cu²⁺ dopant raise the level of the conduction band of pure CdSe QDs, which leads to reduce the charge recombination, enhance the light-harvesting efficiency and improve the charge diffusion and collection. In the same way, we also illustrated photoluminescence decay to determine the lifetime of excited electrons and Electrochemical Impedance Spectra to calculate dynamic resistances in QDSSCs and explain the obtained results.

Keywords: Photovoltaic, Solar energy, EIS, Cu₂S counter electrode.

1. Introduction

In general, quantum dots sensitized solar cells (QDSSCs) originated on the basis of dye sensitized solar cells (DSSCs), instead of dye molecules. This is a narrow band gap (E_g) semiconductor in the type of quantum dots (QDs) which are used as a photo-sensitizer because of their advantages, such as: allowing E_g can be tuned, high molar extinction coefficient, hot electron injection and multiple exciton generation effect^[1-3]. In addition, in view of multiple exciton generation effect the theoretical photovoltaic conversion efficiency can reach up to 44%, which is

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